

Superior High Intensity for High Voltage System

Acrich MJT - 3030 series

SAW9C72B





Product Brief

Description

- This White Colored surface-mount LED comes in standard package dimension. Package Size: 3.0x3.0x0.6mm
- The MJT series of LEDs are designed for AC & DC(High Voltage) operation and high Intensity output applications
- The MJT is ideal light sources for general illumination applications and custom designed solutions
- The package design coupled with careful selection of component materials allow these products to perform with high reliability

Features and Benefits

- High Intensity output and high luminance
- Designed for high voltage operation
- Compact size package
- SMT solderable
- High Color Quality with CRI Min.90(R9>50)
- RoHS compliant

Key Applications

- General lighting
- Replacement lamps
- Architectural
- Commercial

Table 1. Product Selection Table

Dout Name on	сст					
Part Number	Color	Min.	Тур.	Max.		
SAW9C72B	Warm White	2600K	3000K	3700K		



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Performance Characteristics

Table 2. Characteristics, I_F=40mA, T_i= 25°C, RH30%

Parameter	Campbal		Value		Unit
rarameter	Symbol	Min.	Тур.	Max.	Unit
Forward Current	I _F	-	40	60	mA
Forward Voltage	V_{F}	21.5	-	23.5	V
Luminous Intensity ^[1] (2700K) ^[2]	l _v	-	33.5 (103.2)	-	cd (lm)
CRI [3]	R_a	90	-	-	Deg.
Viewing Angle	2Θ _{1/2}	-	120	-	Deg.
Storage Temperature	T_{stg}	- 40	-	+ 100	°C
Thermal resistance (J to S) [4]	$R\theta_{J-S}$	-	16	-	°C/W
ESD Sensitivity(HBM)	-		Class 3A JES	D22-A114-E	

Table 3. Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Forward Current	l _F	60	mA
Pulse Forward Current [5]	I _{FP}	90	mA
Power Dissipation	P_{D}	1.5	W
Junction Temperature	T _j	125	°C
Operating Temperature	T _{opr}	-40 ~ + 85	°C
Storage Temperature	T _{stg}	-40 ~ + 100	°C

Notes:

- (1) Seoul Semiconductor maintains a tolerance of $\pm 7\%$ on Intensity and power measurements.
- (2) Correlated Color Temperature is derived from the CIE 1931 Chromaticity diagram.

Color coordinate : ± 0.005 , CCT $\pm 5\%$ tolerance.

- (3) Tolerance is ±2.0 on CRI measurements.
- (4) Thermal resistance: Rth_{JS} (Junction to Solder)
- (5) I_{FP} conditions with pulse width ≤10ms and duty cycle ≤10%
- Calculated performance values are for reference only.
- Thermal resistance can be increased substantially depending on the heat sink design/operating condition, and the maximum possible driving current will decrease accordingly.
- · All measurements were made under the standardized environment of Seoul Semiconductor.

Fig 1. Color Spectrum, T_i = 25°C, I_F=40mA

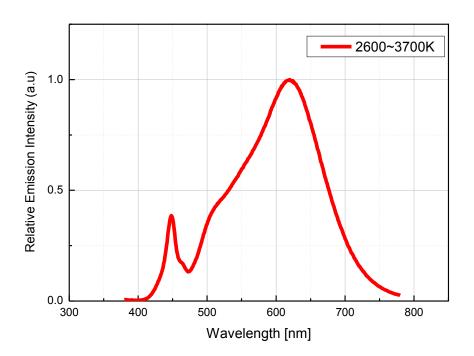


Fig 2. Radiant Pattern, T_i = 25°C, I_F=40mA

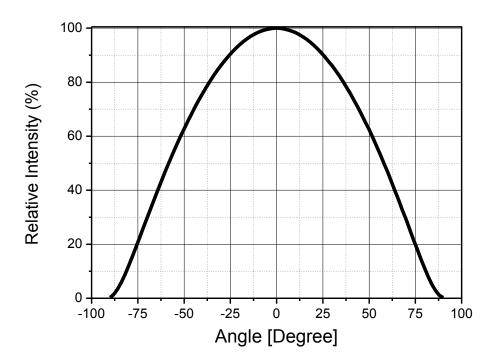


Fig 3. Forward Voltage vs. Forward Current, $T_j = 25^{\circ}C$

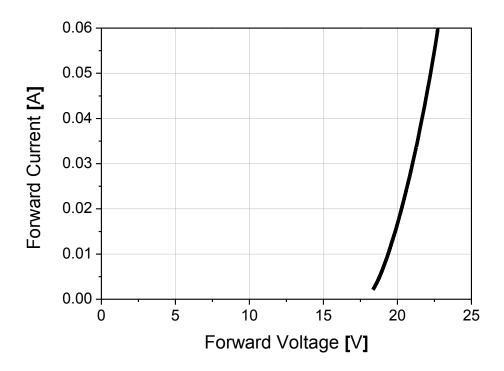


Fig 4. Forward Current vs. Relative Luminous Intensity, T_i = 25°C

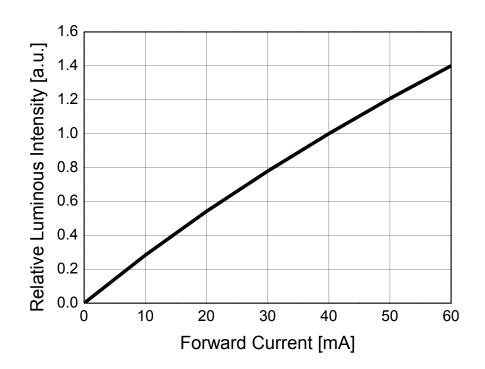
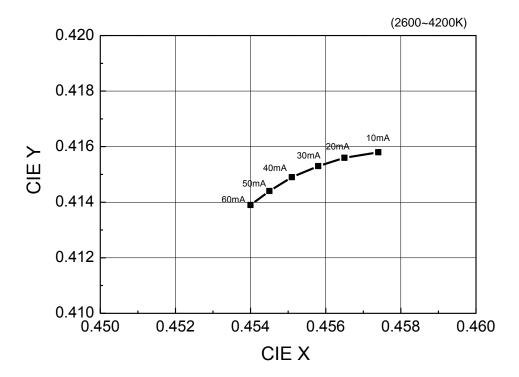


Fig 5. Forward Current vs. CIE X,Y Shift, $T_j = 25^{\circ}C$



Characteristics Graph

SEOUL

Fig 6. Junction Temperature vs. Relative Luminous Intensity, I_F=40mA

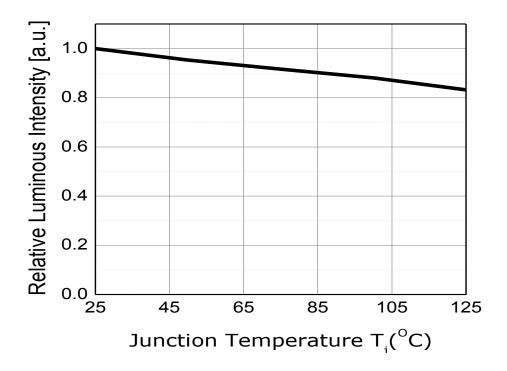


Fig 7. Junction Temperature vs. Relative Forward Voltage, I_F=40mA

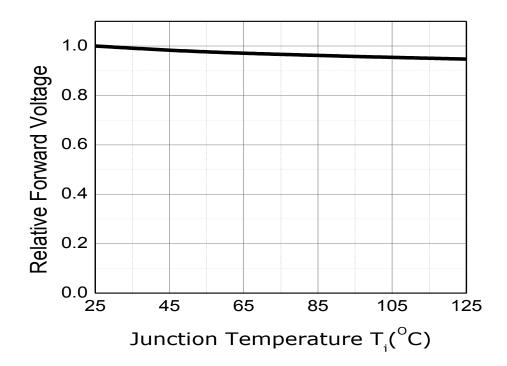


Fig 8. Chromaticity Coordinate vs. Junction Temperature, I_F=40mA

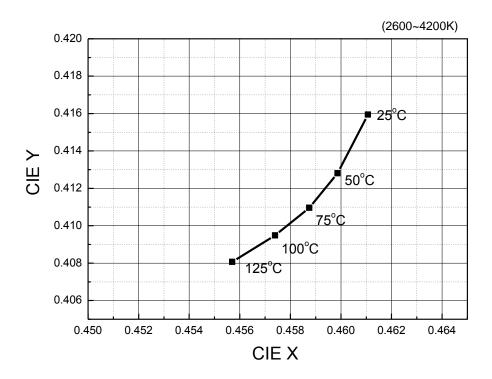
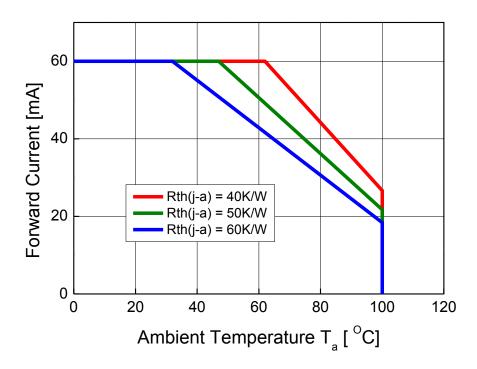


Fig 9. Ambient Temperature vs. Maximum Forward Current, $T_{j_max} = 125^{\circ}C$



Color Bin Structure

Table 4. Bin Code description, T_i=25°C, I_F=40mA

Part	Lu	minous FI (lm) ^[1]	ux	Luminous Intensity (cd) ^[2]		Color Chromaticity	Тур	ical Forw Voltage (V)	ard
Number	Bin Code	Min.	Max.	Min.	Max.	Coordinate	Bin Code	Min.	Max.
	L31	95	101	30.8	32.7		D1	21.5	22.5
SAW9C72B	L33	101	107	32.7	34.7	Refer to	D2	22.5	23.5
3AW9072B	L35	107	113	34.7	36.6	Page. 11~14			
	L37	113	120	36.6	38.9	•			

Table 5. Intensity rank distribution

Available ranks

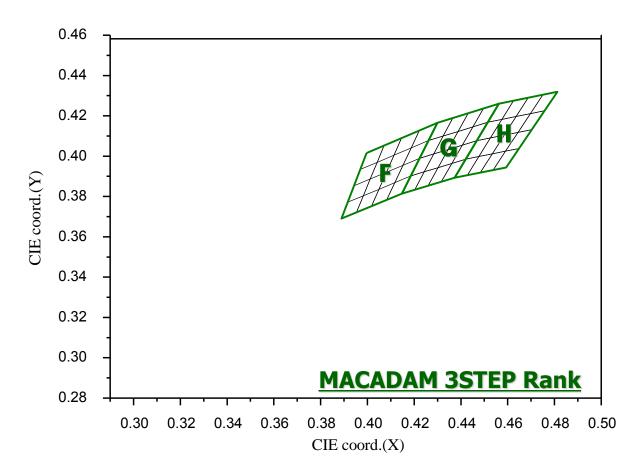
сст	CIE		IV F	Rank	
3200 ~ 3700K	F	L31	L33	L35	L37
2900 ~ 3200K	G	L31	L33	L35	L37
2600 ~ 2900K	Н	L31	L33	L35	L37

*Notes:

- (1) Calculated performance values are for reference only.
- (2) Luminous Intensity values are based on CCT 2700K.
- All measurements were made under the standardized environment of Seoul Semiconductor.
 In order to ensure availability, single color rank will not be orderable.

Color Bin Structure

CIE Chromaticity Diagram T_i=25°C, I_F=40mA

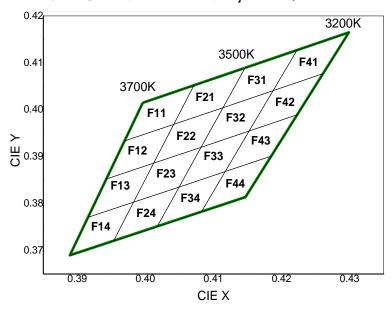


*Notes:

- (1) Energy Star binning applied to all 2600~3700K.
- (2) Measurement Uncertainty of the Color Coordinates : \pm 0.005

Color Bin Structure

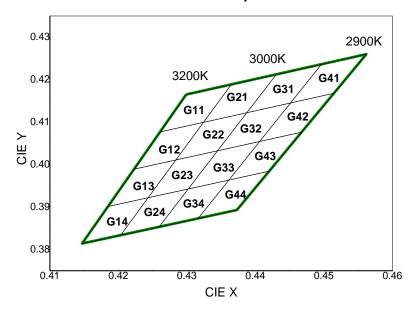
CIE Chromaticity Diagram (Warm white), $T_j=25$ °C, $I_F=40$ mA



F′	11	F:	21	F3	31	F4	41
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.3996	0.4015	0.4071	0.4052	0.4146	0.4089	0.4223	0.4127
0.3969	0.3934	0.4042	0.3969	0.4114	0.4005	0.4187	0.4041
0.4042	0.3969	0.4114	0.4005	0.4187	0.4041	0.4261	0.4077
0.4071	0.4052	0.4146	0.4089	0.4223	0.4127	0.4299	0.4165
F	12	F:	22	F3	32	F4	42
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.3969	0.3934	0.4042	0.3969	0.4114	0.4005	0.4187	0.4041
0.3943	0.3853	0.4012	0.3886	0.4082	0.3920	0.4152	0.3955
0.4012	0.3886	0.4082	0.3920	0.4152	0.3955	0.4223	0.3990
0.4042	0.3969	0.4114	0.4005	0.4187	0.4041	0.4261	0.4077
F ²	13	F:	23	F3	33	F4	43
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.3943	0.3853	0.4012	0.3886	0.4082	0.3920	0.4152	0.3955
0.3916	0.3771	0.3983	0.3803	0.4049	0.3836	0.4117	0.3869
0.3983	0.3803	0.4049	0.3836	0.4117	0.3869	0.4185	0.3902
0.4012	0.3886	0.4082	0.3920	0.4152	0.3955	0.4223	0.3990
F'	14	F.	24	F3	34	F	44
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.3916	0.3771	0.3983	0.3803	0.4049	0.3836	0.4117	0.3869
0.3889	0.3690	0.3953	0.3721	0.4017	0.3751	0.4082	0.3783
0.3953	0.3721	0.4017	0.3751	0.4082	0.3783	0.4147	0.3814
0.3983	0.3803	0.4049	0.3836	0.4117	0.3869	0.4185	0.3902

Color Bin Structure

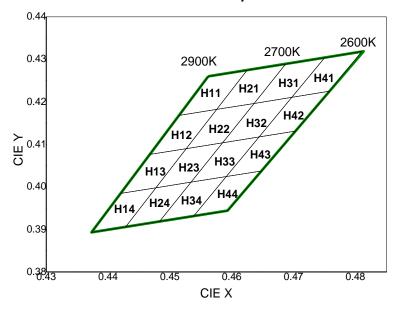
CIE Chromaticity Diagram (Warm white), T_i=25°C, I_F=40mA



G _′	11	G	21	G3	31	G	41
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.4299	0.4165	0.4364	0.4188	0.4430	0.4212	0.4496	0.4236
0.4261	0.4077	0.4324	0.4099	0.4387	0.4122	0.4451	0.4145
0.4324	0.4100	0.4387	0.4122	0.4451	0.4145	0.4514	0.4168
0.4365	0.4189	0.4430	0.4212	0.4496	0.4236	0.4562	0.4260
G ²	12	G	22	G3	32	G.	42
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.4261	0.4077	0.4324	0.4100	0.4387	0.4122	0.4451	0.4145
0.4223	0.3990	0.4284	0.4011	0.4345	0.4033	0.4406	0.4055
0.4284	0.4011	0.4345	0.4033	0.4406	0.4055	0.4468	0.4077
0.4324	0.4100	0.4387	0.4122	0.4451	0.4145	0.4515	0.4168
G [,]	13	G	23	G	33	G.	43
G' CIE X	13 CIE Y	G: CIE X	CIE Y	CIE X	CIE Y	G/ CIE X	43 CIE Y
-							
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
CIE X 0.4223	CIE Y 0.3990	CIE X 0.4284	CIE Y 0.4011	CIE X 0.4345	CIE Y 0.4033	CIE X 0.4406	CIE Y 0.4055
CIE X 0.4223 0.4185	CIE Y 0.3990 0.3902	CIE X 0.4284 0.4243	CIE Y 0.4011 0.3922	CIE X 0.4345 0.4302	CIE Y 0.4033 0.3943	CIE X 0.4406 0.4361	CIE Y 0.4055 0.3964
CIE X 0.4223 0.4185 0.4243	CIE Y 0.3990 0.3902 0.3922 0.4011	CIE X 0.4284 0.4243 0.4302 0.4345	CIE Y 0.4011 0.3922 0.3943	CIE X 0.4345 0.4302 0.4361	CIE Y 0.4033 0.3943 0.3964 0.4055	O.4406 0.4361 0.4420	CIE Y 0.4055 0.3964 0.3985 0.4077
CIE X 0.4223 0.4185 0.4243 0.4284	CIE Y 0.3990 0.3902 0.3922 0.4011	CIE X 0.4284 0.4243 0.4302 0.4345	CIE Y 0.4011 0.3922 0.3943 0.4033	CIE X 0.4345 0.4302 0.4361 0.4406	CIE Y 0.4033 0.3943 0.3964 0.4055	CIE X 0.4406 0.4361 0.4420 0.4468	CIE Y 0.4055 0.3964 0.3985 0.4077
CIE X 0.4223 0.4185 0.4243 0.4284	CIE Y 0.3990 0.3902 0.3922 0.4011	CIE X 0.4284 0.4243 0.4302 0.4345	CIE Y 0.4011 0.3922 0.3943 0.4033	CIE X 0.4345 0.4302 0.4361 0.4406	CIE Y 0.4033 0.3943 0.3964 0.4055	CIE X 0.4406 0.4361 0.4420 0.4468	CIE Y 0.4055 0.3964 0.3985 0.4077
CIE X 0.4223 0.4185 0.4243 0.4284 G* CIE X	CIE Y 0.3990 0.3902 0.3922 0.4011 14 CIE Y	CIE X 0.4284 0.4243 0.4302 0.4345 G: CIE X	CIE Y 0.4011 0.3922 0.3943 0.4033 24 CIE Y	CIE X 0.4345 0.4302 0.4361 0.4406 GS CIE X	CIE Y 0.4033 0.3943 0.3964 0.4055	CIE X 0.4406 0.4361 0.4420 0.4468 G: CIE X	CIE Y 0.4055 0.3964 0.3985 0.4077 44 CIE Y
CIE X 0.4223 0.4185 0.4243 0.4284 G* CIE X 0.4243	CIE Y 0.3990 0.3902 0.3922 0.4011 14 CIE Y 0.3922	CIE X 0.4284 0.4243 0.4302 0.4345 G: CIE X 0.4302	CIE Y 0.4011 0.3922 0.3943 0.4033 24 CIE Y 0.3943	CIE X 0.4345 0.4302 0.4361 0.4406 CIE X 0.4302	CIE Y 0.4033 0.3943 0.3964 0.4055 44 CIE Y 0.3943	CIE X 0.4406 0.4361 0.4420 0.4468 GCIE X 0.4361	CIE Y 0.4055 0.3964 0.3985 0.4077 44 CIE Y 0.3964

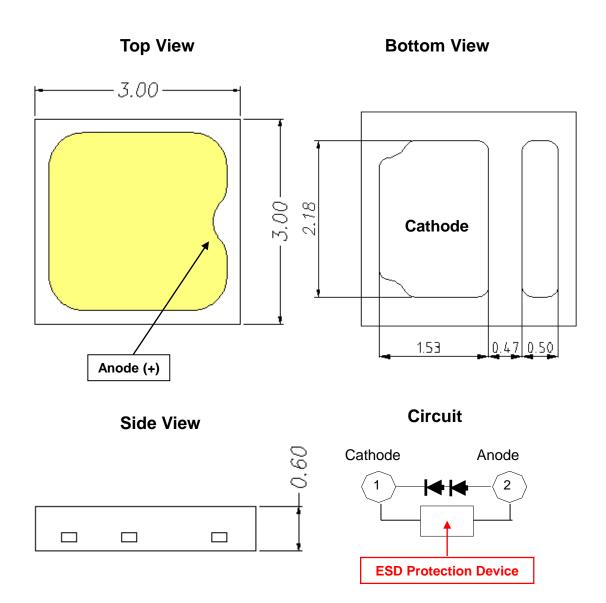
Color Bin Structure

CIE Chromaticity Diagram (Warm white), T_i=25°C, I_F=40mA



Н	11	н	21	H	31	H	41
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.4562	0.4260	0.4625	0.4275	0.4687	0.4289	0.4750	0.4304
0.4515	0.4168	0.4575	0.4182	0.4636	0.4197	0.4697	0.4211
0.4575	0.4182	0.4636	0.4197	0.4697	0.4211	0.4758	0.4225
0.4625	0.4275	0.4687	0.4289	0.4750	0.4304	0.4810	0.4319
H	12	н	22	H:	32	H	42
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.4515	0.4168	0.4575	0.4182	0.4636	0.4197	0.4697	0.4211
0.4468	0.4077	0.4526	0.4090	0.4585	0.4104	0.4644	0.4118
0.4526	0.4090	0.4585	0.4104	0.4644	0.4118	0.4703	0.4132
0.4575	0.4182	0.4636	0.4197	0.4697	0.4211	0.4758	0.4225
H	13	н	23	H	33	H	43
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.4468	0.4077	0.4526	0.4090	0.4585	0.4104	0.4644	0.4118
0.4420	0.3985	0.4477	0.3998	0.4534	0.4012	0.4591	0.4025
0.4477	0.3998	0.4534	0.4012	0.4591	0.4025	0.4648	0.4038
0.4526	0.4090	0.4585	0.4104	0.4644	0.4118	0.4703	0.4132
H	14	н	24	H:	34	H	44
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.4420	0.0005	0.4477	0.3998	0.4534	0.4012	0.4591	0.4025
0.4420	0.3985	0.4477	0.5550	0.1001			
0.4420	0.3985	0.4477	0.3906	0.4483	0.3919	0.4538	0.3932
						0.4538 0.4593	0.3932 0.3944

Mechanical Dimensions



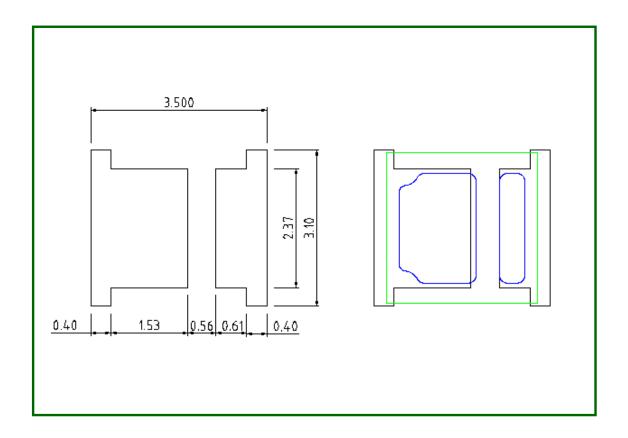
Notes:

(1) All dimensions are in millimeters.

(2) Scale: none

(3) Undefined tolerance is $\pm 0.2 mm$

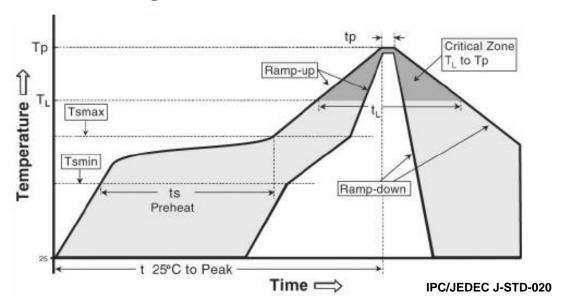
Recommended Solder Pad



Notes:

- (1) All dimensions are in millimeters.
- (2) Scale: none
- (3) This drawing without tolerances are for reference only
- (4) Undefined tolerance is ± 0.1 mm
- (5) The appearance and specifications of the product may be changed for improvement without notice.

Reflow Soldering Characteristics

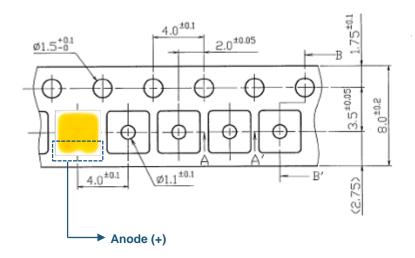


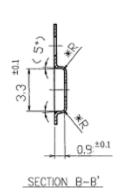
Profile Feature	Sn-Pb Eutectic Assembly	Pb-Free Assembly
Average ramp-up rate (T _{s_max} to T _p)	3° C/second max.	3° C/second max.
$ \begin{array}{c} \textbf{Preheat} \\ \textbf{- Temperature Min } (\textbf{T}_{\text{S_min}}) \\ \textbf{- Temperature Max } (\textbf{T}_{\text{S_max}}) \\ \textbf{- Time } (\textbf{T}_{\text{S_min}} \ \text{to } \textbf{T}_{\text{S_max}}) \ (\textbf{t}_{\text{S}}) \\ \end{array} $	100 °C 150 °C 60-120 seconds	150 °C 200 °C 60-180 seconds
Time maintained above: - Temperature (T _L) - Time (t _L)	183 °C 60-150 seconds	217 °C 60-150 seconds
Peak Temperature (T _p)	215℃	260℃
Time within 5°C of actual Peak Temperature (t _p)2	10-30 seconds	20-40 seconds
Ramp-down Rate	6 °C/second max.	6 °C/second max.
Time 25°C to Peak Temperature	6 minutes max.	8 minutes max.

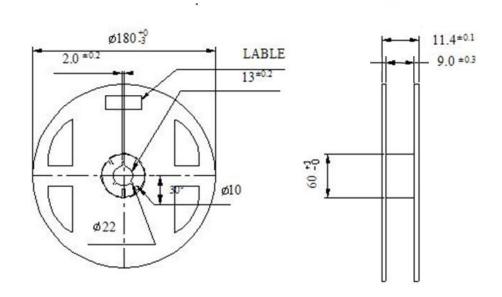
Caution:

- (1) Reflow soldering is recommended not to be done more than two times
 In the case of more than 24 hours passed soldering after first, LEDs will be damaged.
- (2) Repairs should not be done after the LEDs have been soldered When repair is unavoidable, suitable tools must be used.
- (3) Die slug is to be soldered.
- (4) When soldering, do not put stress on the LEDs during heating.
- (5) After soldering, do not warp the circuit board.

Emitter Tape & Reel Packaging







(Tolerance: ± 0.2 , Unit: mm)

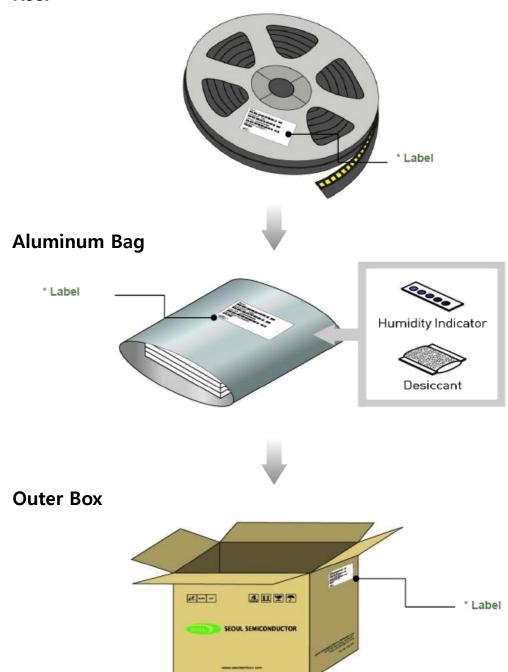
Notes:

- (1) Quantity: Max 4,500pcs/Reel
- (2) Cumulative Tolerance : Cumulative Tolerance/10 pitches to be ± 0.2 mm
- (3) Adhesion Strength of Cover Tape

 Adhesion strength to be 0.1-0.7N when the cover tape is turned off from the carrier tape at the angle of 10° to the carrier tape.
- (4) Package: P/N, Manufacturing data Code No. and Quantity to be indicated on a damp proof Package.

Emitter Tape & Reel Packaging

Reel



Product Nomenclature

Table 6. Part Numbering System : $X_1X_2X_3X_4X_5X_6X_7X_8$

Part Number Code	Description	Part Number	Value
X ₁	Company	S	SSC
X ₂	Top View LED series	А	Acrich
X ₃ X ₄	Color Specification	W9	CRI 90
X ₅	Package series	С	3030 Series
X ₆ X ₇	Characteristic code	72	
X ₈	Revision	В	

Table 7. Lot Numbering System $: Y_1Y_2Y_3Y_4Y_5Y_6Y_7Y_8Y_9Y_{10} - Y_{11}Y_{12}Y_{13}Y_{14}Y_{15}Y_{16}Y_{17}$

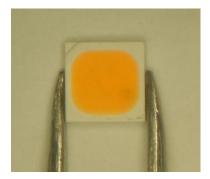
Lot Number Code	Description	Lot Number	Value
Y ₁ Y ₂	Year		
Y ₃	Month		
Y ₄ Y ₅	Day		
Y ₆	Top View LED series		
Y ₇ Y ₈ Y ₉ Y ₁₀	Mass order		
Y ₁₁ Y ₁₂ Y ₁₃ Y ₁₄ Y ₁₅ Y ₁₆ Y ₁₇	Internal Number		

Handling of Silicone Resin for LEDs

(1) During processing, mechanical stress on the surface should be minimized as much as possible. Sharp objects of all types should not be used to pierce the sealing compound.



(2) In general, LEDs should only be handled from the side. By the way, this also applies to LEDs without a silicone sealant, since the surface can also become scratched.



- (3) When populating boards in SMT production, there are basically no restrictions regarding the form of the pick and place nozzle, except that mechanical pressure on the surface of the resin must be prevented. This is assured by choosing a pick and place nozzle which is larger than the LED's reflector area.
- (4) Silicone differs from materials conventionally used for the manufacturing of LEDs. These conditions must be considered during the handling of such devices. Compared to standard encapsulants, silicone is generally softer, and the surface is more likely to attract dust.

As mentioned previously, the increased sensitivity to dust requires special care during processing. In cases where a minimal level of dirt and dust particles cannot be guaranteed, a suitable cleaning solution must be applied to the surface after the soldering of components.

- (5) SSC suggests using isopropyl alcohol for cleaning. In case other solvents are used, it must be assured that these solvents do not dissolve the package or resin.

 Ultrasonic cleaning is not recommended. Ultrasonic cleaning may cause damage to the LED.
- (6) Please do not mold this product into another resin (epoxy, urethane, etc) and do not handle this. product with acid or sulfur material in sealed space.

Precaution for Use

(1) Storage

To avoid the moisture penetration, we recommend store in a dry box with a desiccant. The recommended storage temperature range is 5°C to 30°C and a maximum humidity of RH50%.

(2) Use Precaution after Opening the Packaging

Use SMT techniques properly when you solder the LED as separation of the lens may affect the light output efficiency.

Pay attention to the following:

- a. Recommend conditions after opening the package
 - Sealing / Temperature : 5 ~ 40°C Humidity : less than RH30%
- b. If the package has been opened more than 4 week(MSL_2a) or the color of the desiccant changes, components should be dried for 10-12hr at $60\pm5^{\circ}$ C
- (3) Do not apply mechanical force or excess vibration during the cooling process to normal temperature after soldering.
- (4) Do not rapidly cool device after soldering.
- (5) Components should not be mounted on warped (non coplanar) portion of PCB.
- (6) Radioactive exposure is not considered for the products listed here in.
- (7) Gallium arsenide is used in some of the products listed in this publication. These products are dangerous if they are burned or shredded in the process of disposal. It is also dangerous to drink the liquid or inhale the gas generated by such products when chemically disposed of.
- (8) This device should not be used in any type of fluid such as water, oil, organic solvent and etc. When washing is required, IPA (Isopropyl Alcohol) should be used.
- (9) When the LEDs are in operation the maximum current should be decided after measuring the package temperature.
- (10) LEDs must be stored properly to maintain the device. If the LEDs are stored for 3 months or more after being shipped from SSC, a sealed container with a nitrogen atmosphere should be used for storage.

Precaution for Use

- (11) The appearance and specifications of the product may be modified for improvement without notice.
- (12) Long time exposure of sunlight or occasional UV exposure will cause lens discoloration.
- (13) VOCs (Volatile organic compounds) emitted from materials used in the construction of fixtures can penetrate silicone encapsulants of LEDs and discolor when exposed to heat and photonic energy. The result can be a significant loss of light output from the fixture. Knowledge of the properties of the materials selected to be used in the construction of fixtures can help prevent these issues.
- (14) Attaching LEDs, do not use adhesives that outgas organic vapor.
- (15) The driving circuit must be designed to allow forward voltage only when it is ON or OFF.
 If the reverse voltage is applied to LED, migration can be generated resulting in LED damage.
- (16) Similar to most Solid state devices;
 LEDs are sensitive to Electro-Static Discharge (ESD) and Electrical Over Stress (EOS).
 Below is a list of suggestions that Seoul Semiconductor purposes to minimize these effects.
- a. ESD (Electro Static Discharge)

Electrostatic discharge (ESD) is the defined as the release of static electricity when two objects come into contact. While most ESD events are considered harmless, it can be an expensive problem in many industrial environments during production and storage. The damage from ESD to an LEDs may cause the product to demonstrate unusual characteristics such as:

- Increase in reverse leakage current lowered turn-on voltage
- Abnormal emissions from the LED at low current

The following recommendations are suggested to help minimize the potential for an ESD event. One or more recommended work area suggestions:

- Ionizing fan setup
- ESD table/shelf mat made of conductive materials
- ESD safe storage containers

One or more personnel suggestion options:

- Antistatic wrist-strap
- Antistatic material shoes
- Antistatic clothes

Environmental controls:

- Humidity control (ESD gets worse in a dry environment)



Precaution for Use

b. EOS (Electrical Over Stress)

Electrical Over-Stress (EOS) is defined as damage that may occur when an electronic device is subjected to a current or voltage that is beyond the maximum specification limits of the device. The effects from an EOS event can be noticed through product performance like:

- Changes to the performance of the LED package
 (If the damage is around the bond pad area and since the package is completely encapsulated the package may turn on but flicker show severe performance degradation.)
- Changes to the light output of the luminaire from component failure
- Components on the board not operating at determined drive power

Failure of performance from entire fixture due to changes in circuit voltage and current across total circuit causing trickle down failures. It is impossible to predict the failure mode of every LED exposed to electrical overstress as the failure modes have been investigated to vary, but there are some common signs that will indicate an EOS event has occurred:

- Damaged may be noticed to the bond wires (appearing similar to a blown fuse)
- Damage to the bond pads located on the emission surface of the LED package (shadowing can be noticed around the bond pads while viewing through a microscope)
- Anomalies noticed in the encapsulation and phosphor around the bond wires.
- This damage usually appears due to the thermal stress produced during the EOS event.
- c. To help minimize the damage from an EOS event Seoul Semiconductor recommends utilizing:
 - A surge protection circuit
 - An appropriately rated over voltage protection device
 - A current limiting device



Company Information

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Company Information

Seoul Semiconductor (www.SeoulSemicon.com) manufacturers and packages a wide selection of light emitting diodes (LEDs) for the automotive, general illumination/lighting, Home appliance, signage and back lighting markets. The company is the world's fifth largest LED supplier, holding more than 10,000 patents globally, while offering a wide range of LED technology and production capacity in areas such as "nPola", "Acrich", the world's first commercially produced AC LED, and "Acrich MJT - Multi-Junction Technology" a proprietary family of high-voltage LEDs.

The company's broad product portfolio includes a wide array of package and device choices such as Acrich and Acirch2, high-brightness LEDs, mid-power LEDs, side-view LEDs, and through-hole type LEDs as well as custom modules, displays, and sensors.

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